



Developments and applications in Transmission Kikuchi Diffraction

(TKD)

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Acknowledgments to:

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AND APPLICATIONS IN MICROBEAM ANALYSIS

Motivation

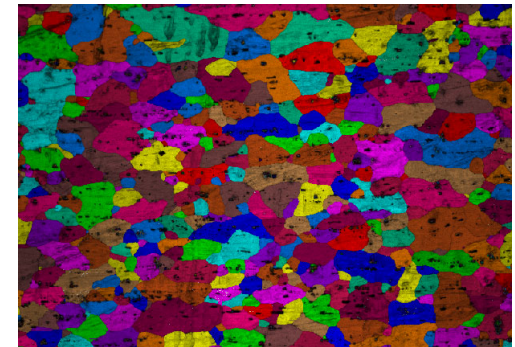
1. Current developments in the sub-micro and nano-scale engineering require new or improved analytical techniques with better spatial resolution.
2. In our case, an improved resolution was needed for grain size and texture mapping of newly developed light alloys (Al and Mg based).

Hot forged 1.5kg towbar example made from sub-micron grain size aluminium alloy



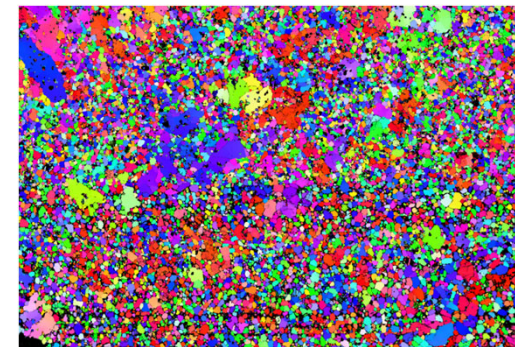
Industrial Al alloy

Average grain size
50 μm



Newly developed Al alloy

Average grain size
700 nm

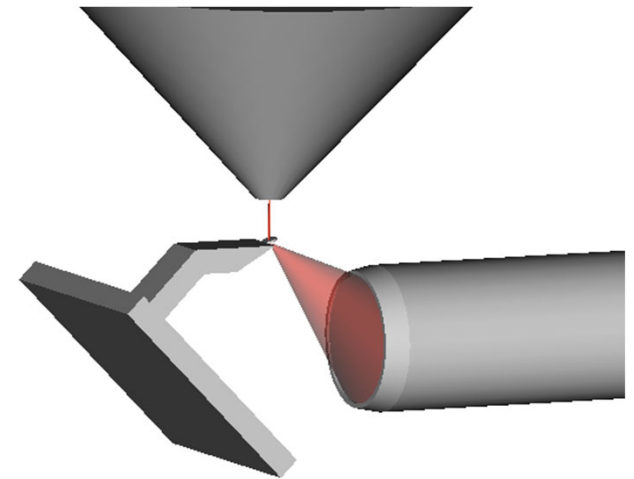


Introduction

1. The TKD is already mature measurement technique employing the same post processing software as EBSD.
2. Any crystalline object with correct thickness (int the range of 50nm to ~500nm) can be used. Examples includes: metals and alloys, ceramic and geological samples, nano-particles, samples for APT
3. Requirements:
 - FEG-SEM
 - Thin-smaple
 - Holder

The goal of the presentation is to show you that TKD can be used as **effectively** as a standard/reflection EBSD.

Topics concerning acqusition geometry, signal intensity, holder design and spatial resolution will be addressed in the talk.



EBSD and TKD spatial resolution example

Lighter (lower Z) samples larger electron-matter interaction volume

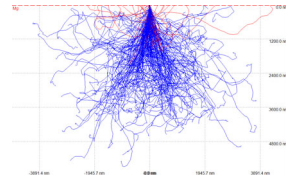
Common solution is to use lower kV.

An example is showing deformed Mg sample where high number of twins with sub-micron thickness.

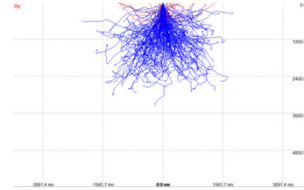
Map step size: 50 nm

EBSD

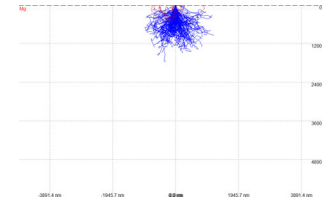
20 kV



15 kV

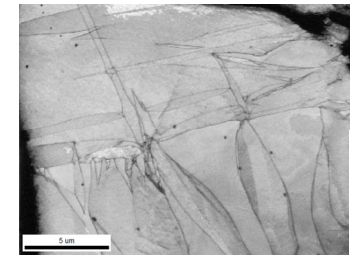
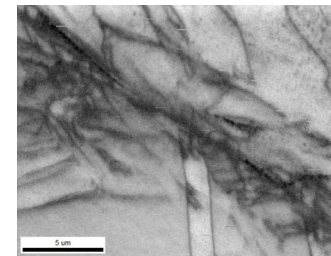
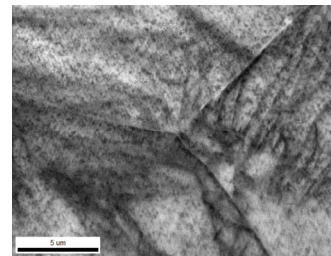
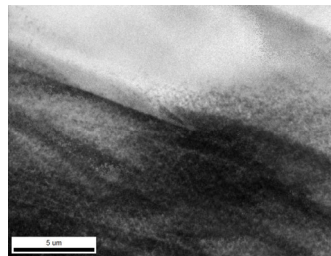
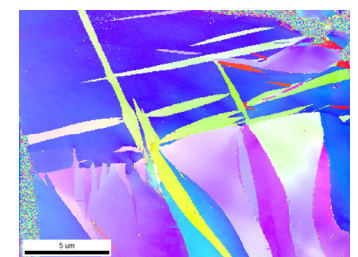
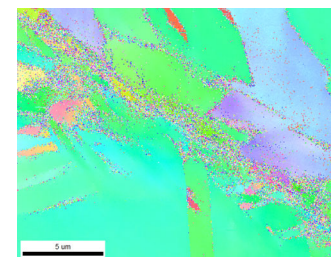
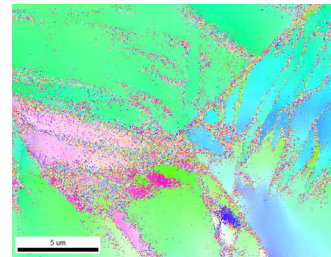
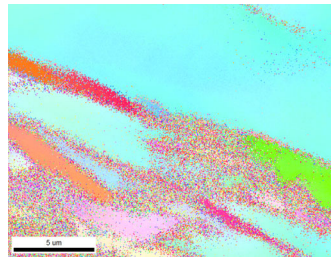
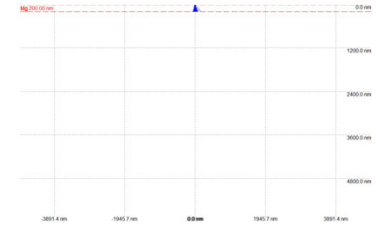


10 kV



TKD

20 kV

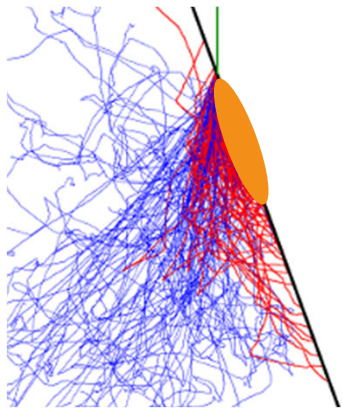


5 um

EBSD signal source

Broad field of view: many reflectors are mapped simultaneously on the detector screen.

FEG-SEM instruments are capable of focusing electron beam down to 1nm in diameter, thus the only limiting factor is the matter interaction volume.

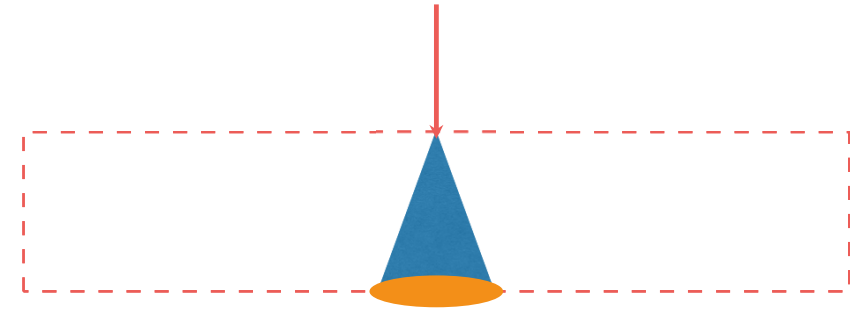


Absorbed electrons
Back-scattered electrons

Area of the useful diffraction signal is much smaller than interaction volume
Spatial resolution is anisotropic due to the sample inclination

EBSD resolution limits:
Heavy elements ~ 50 nm
Light elements ~100 nm

TKD signal source



Electron interaction volume is reduced leading to the improved spatial resolution

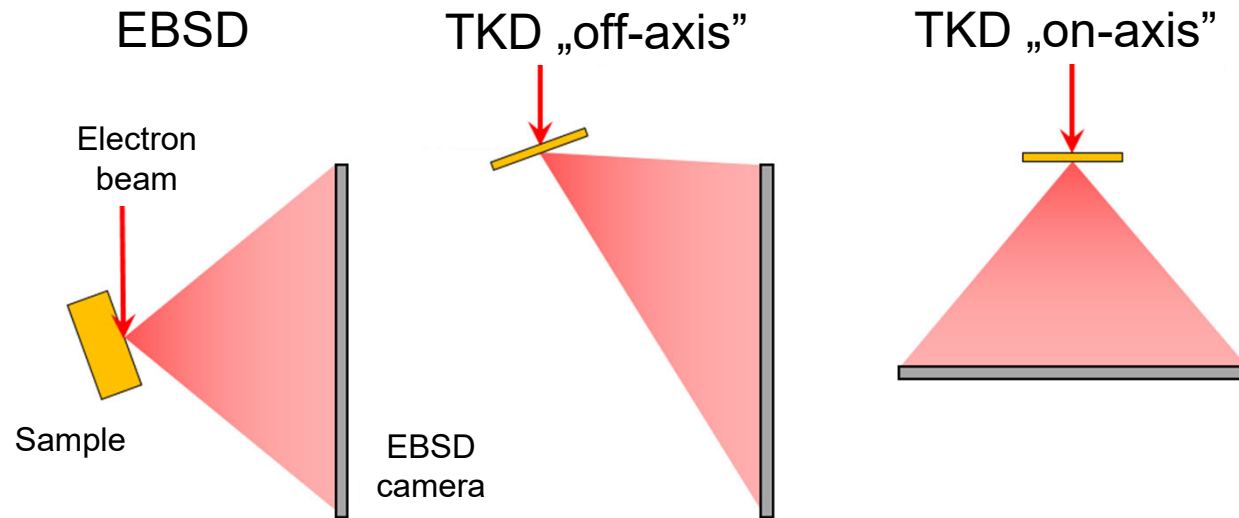
The source of diffraction is located at the bottom surface of the thin foil. Spatial resolution anisotropy is present in the case of “off-axis” TKD.

TKD resolution limits are in the range of 10 to 20 nm



Geometry

TKD configuration



EBSD projection center:

PCx usually around 0.5

PCy in the range of 0.2 to 0.7

PCz in the range of 0.5 to 0.9

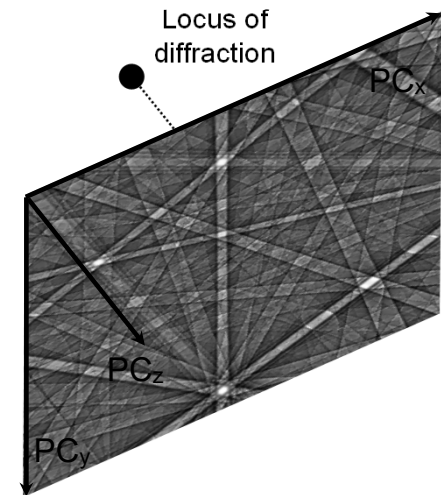
TKD projection center:

PCx usually around 0.5

PCy is negative

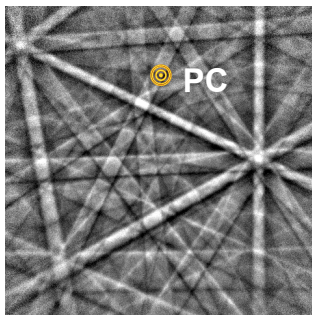
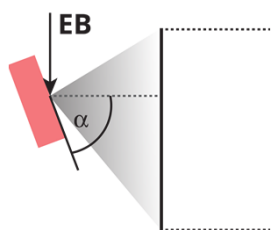
PCz in the range of 0.5 to 0.9

Definition of the Projection Center (PC)

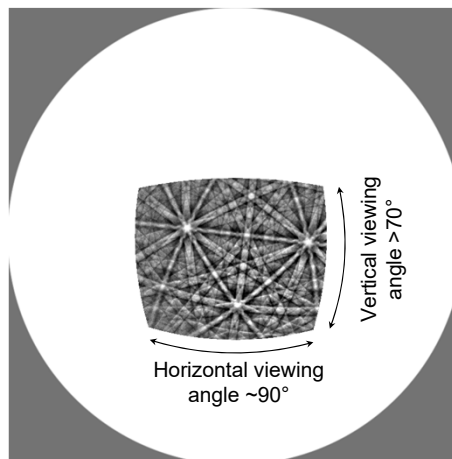


The effects of projection center on registered signal

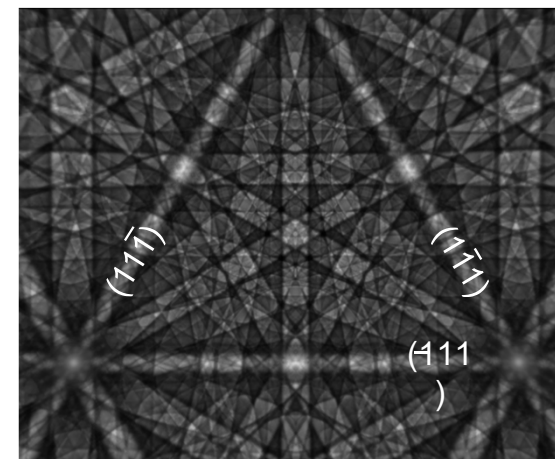
EBSD



Stereographic projection



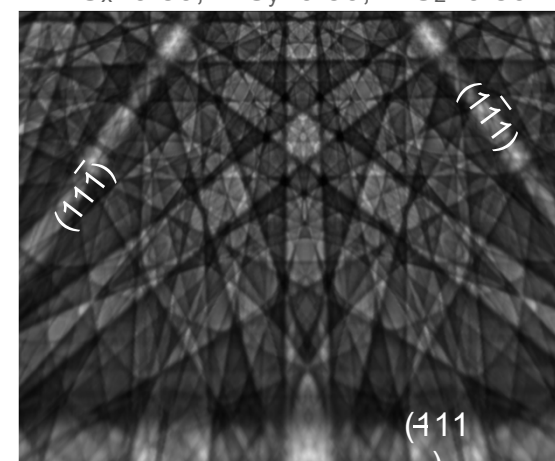
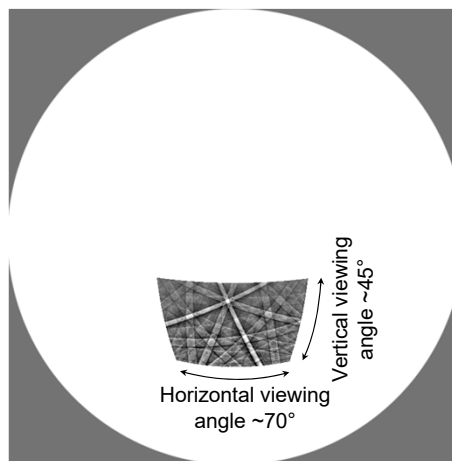
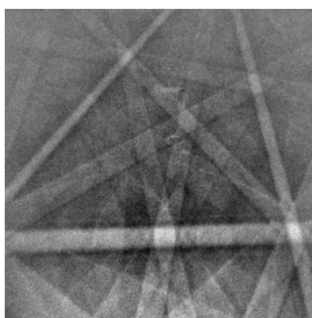
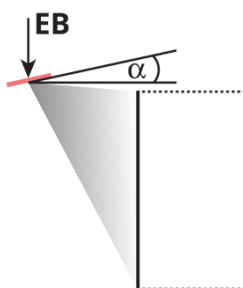
Gnomonic projection



$PC_x=0.50$; $PC_y=0.50$; $PC_z=0.80$

TKD

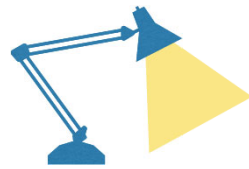
PC



$PC_x=0.50$; $PC_y=-0.40$; $PC_z=0.80$

TKD

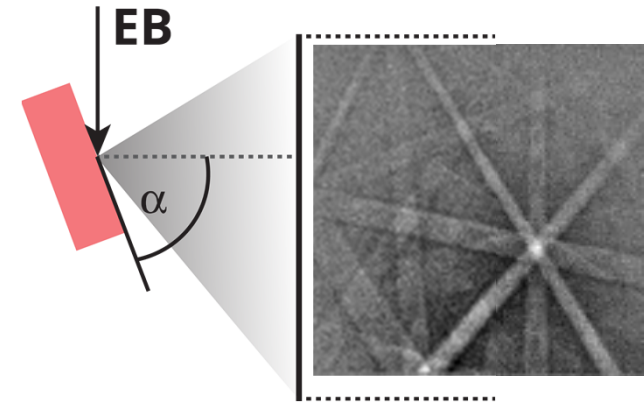
- Smaller viewing angle
- High gnomonic distortions



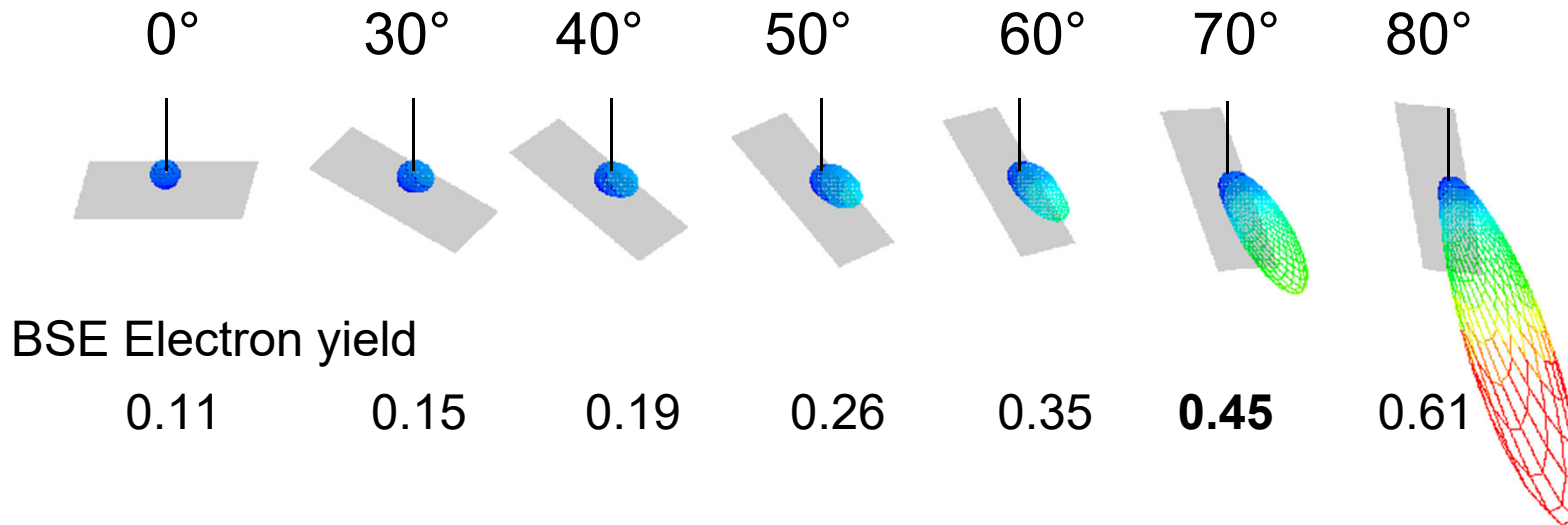
Signal intensity

Sample inclination angle - the best camera performance

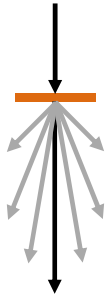
- Angular distribution of electrons changes with the sample inclination
- Optimum inclination is **60° to 70°**
- Electron yield (amount of electrons backscattered) increases with the sample inclination



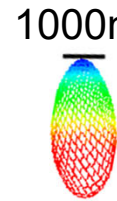
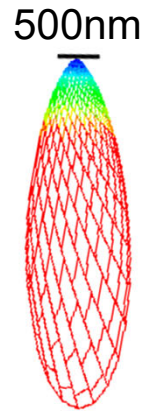
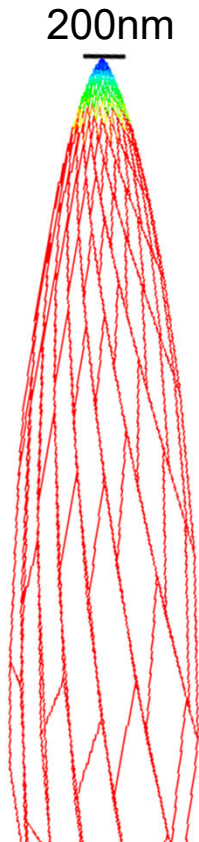
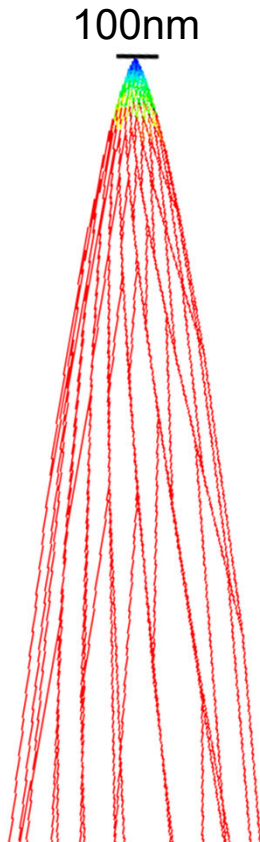
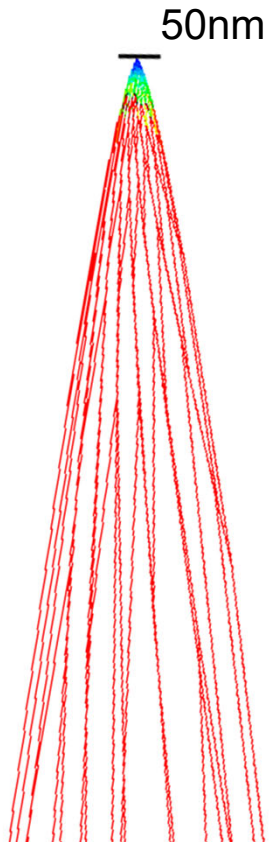
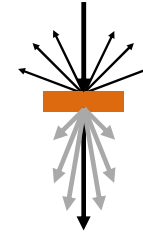
Monte Carlo simulation of back scattered electrons, Mg example.



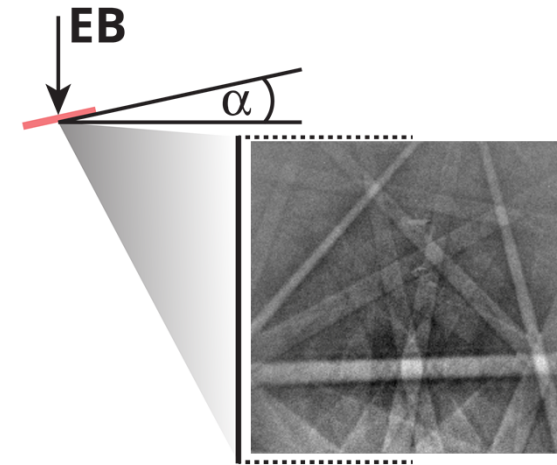
TKD Specimen thickness - electron distribution



- Angular distribution of transmitted electrons changes with the sample thickness
- Electron yield (amount of electrons backscattered) increases with inclination

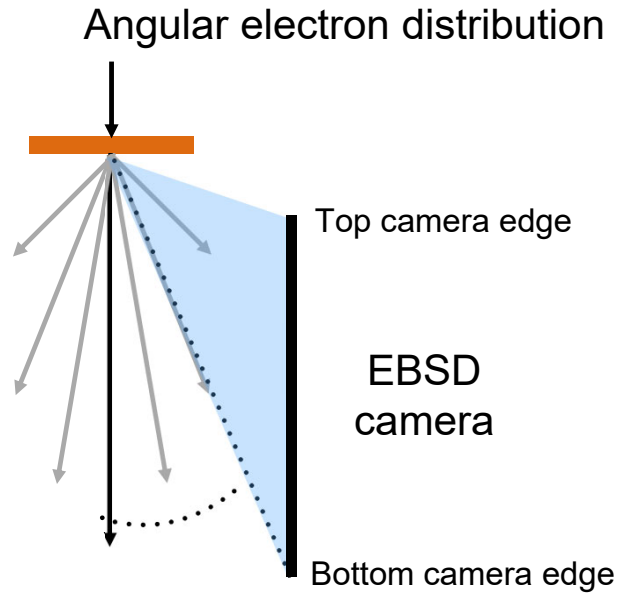


Region of high electron absorption and backscattering, Magnesium sample, Beam energy 20 keV



MC simulation

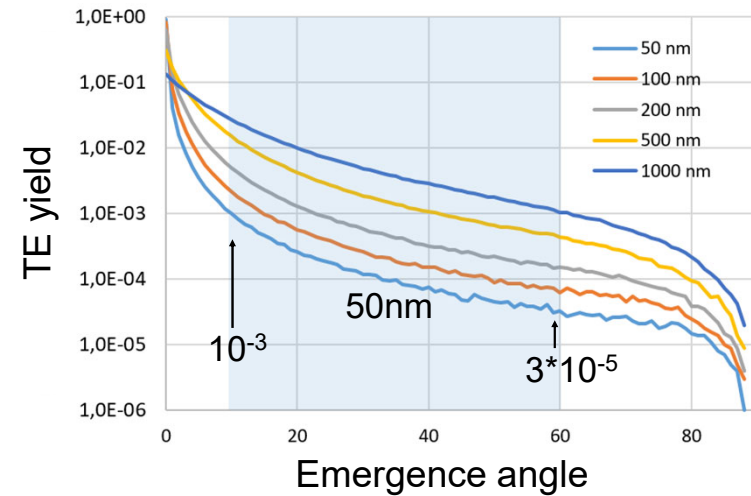
Electron yield in the EBSD camera, Mg sample



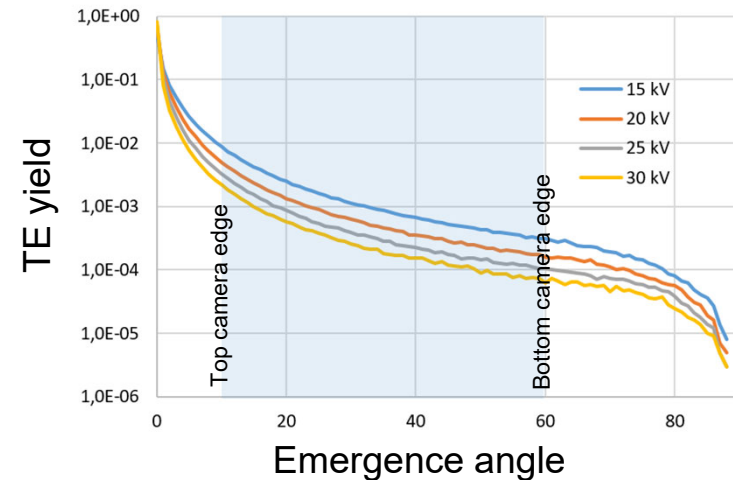
- At higher sample thickness absorption and backscattering effect are becoming significant
- Thinnest sample region offers best spatial resolution but at the same time intensity of the patterns registered in the camera is lowest

Electron yield in camera is very small. For a typical imaging conditions of **20 - 30 keV** and **50 - 300 nm** specimen thickness is in the range of **0.01 to 0.1**

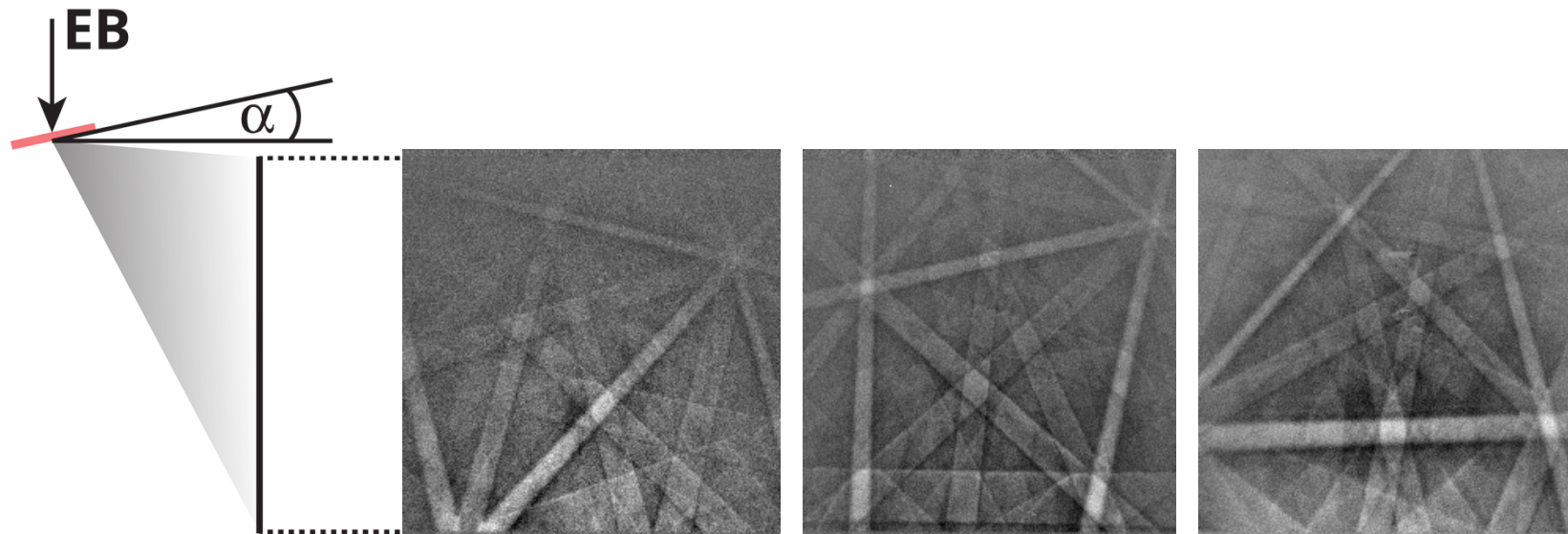
Thickness variation, 30kV



kV variation, 100nm



Effect of thin foil inclination

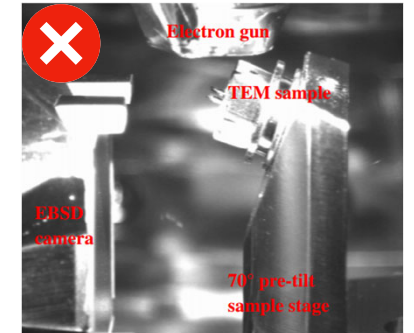
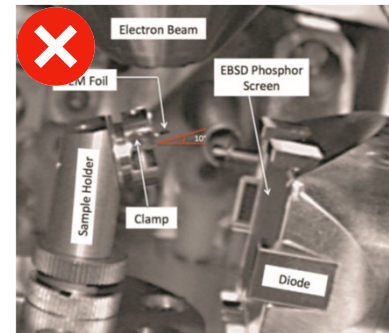
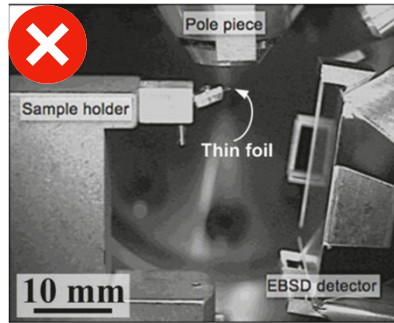
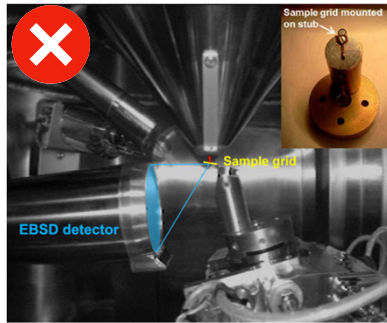
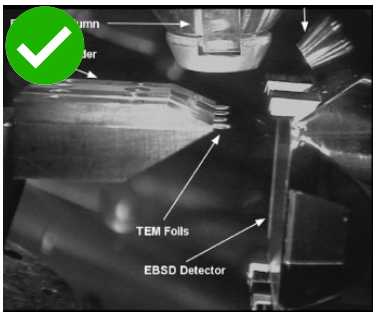
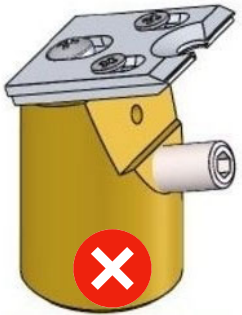
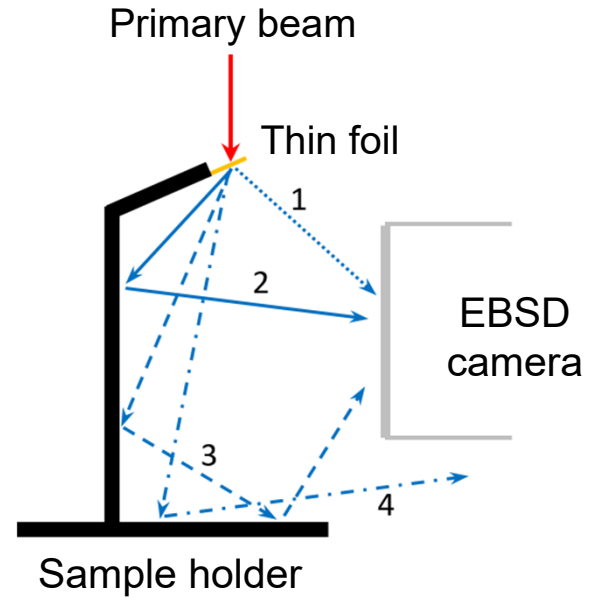
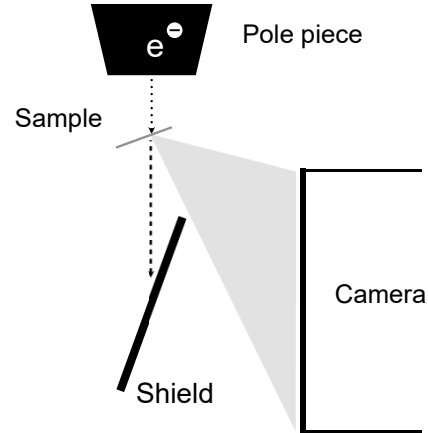
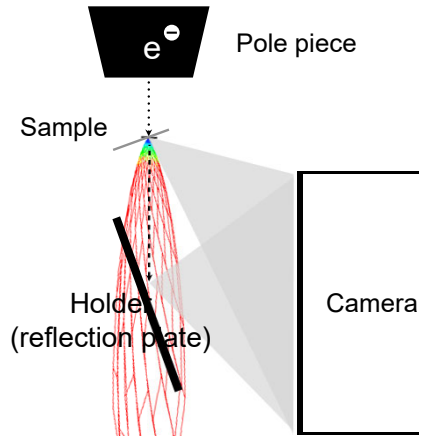


- Depending on microscope setup, inclination may be required to prevent shadowing effect
- Foil is inclined at negative angles with respect to standard EBSD
- Foil inclination slightly increase electron yield in the camera



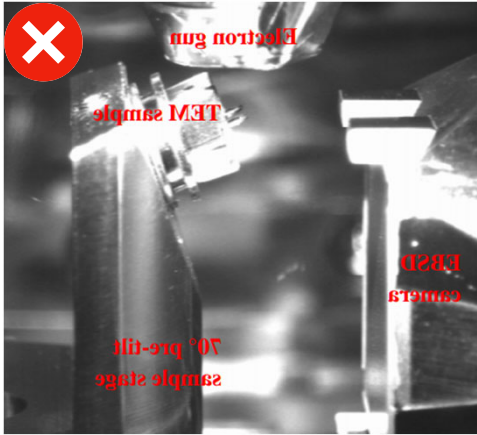
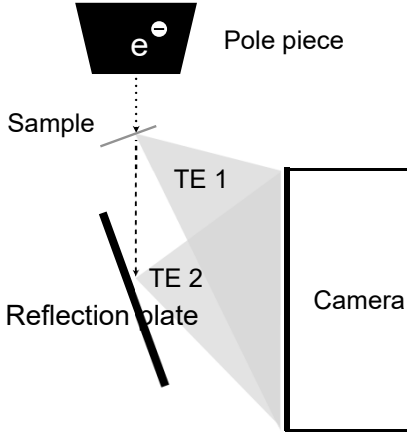
Holder with a shield

The idea of shielded holder - do we need shielding?

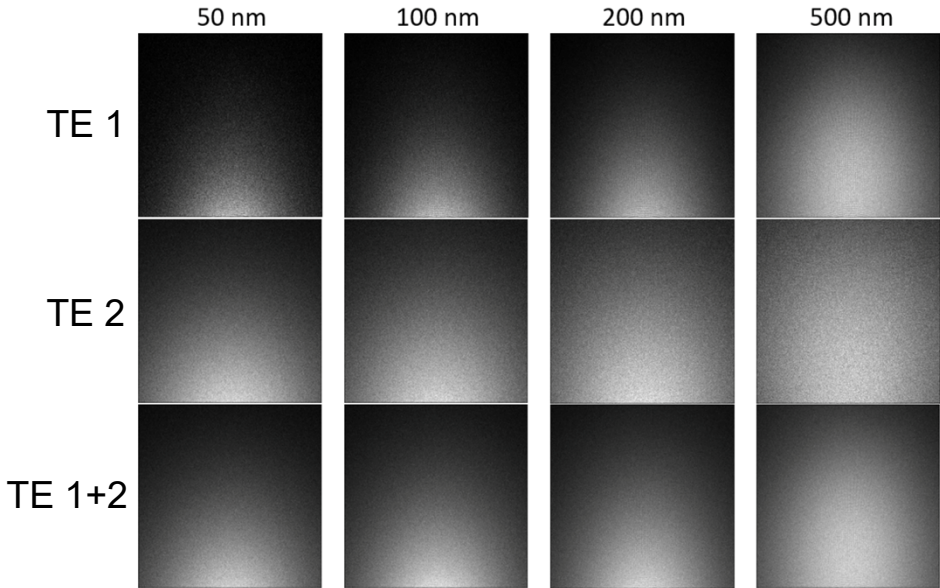


Examples from literature

Parasitic electrons intensity



Monte Carlo simulations, Mg thin foil

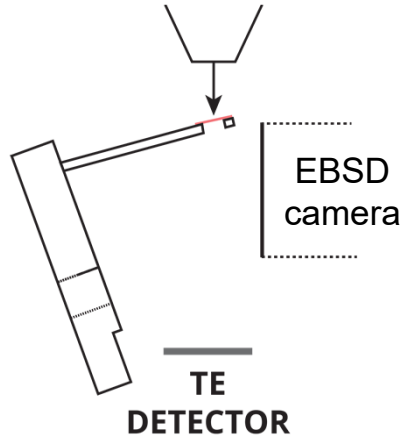


Worst case scenario!!!

Foil thickness, nm	50	100	200	500
	Fraction of electrons in the camera			
TE 1	0,011	0,022	0,049	0,110
TE 2	0,058	0,058	0,058	0,045
Parasitic interference, %	84,1	72,5	54,2	29,0

TKD holder example

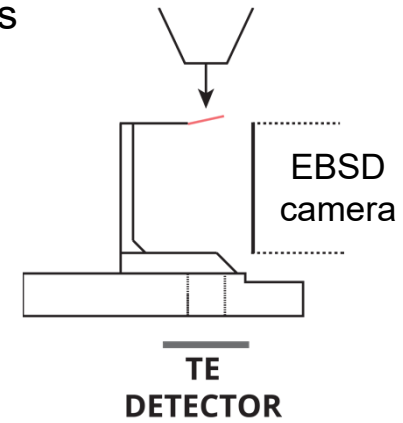
Tilted stage



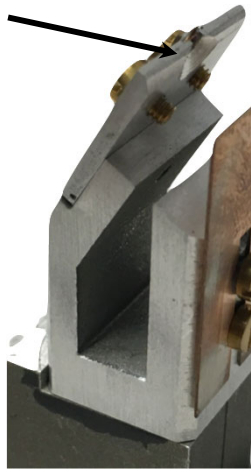
All possible configurations
with pretilted holder



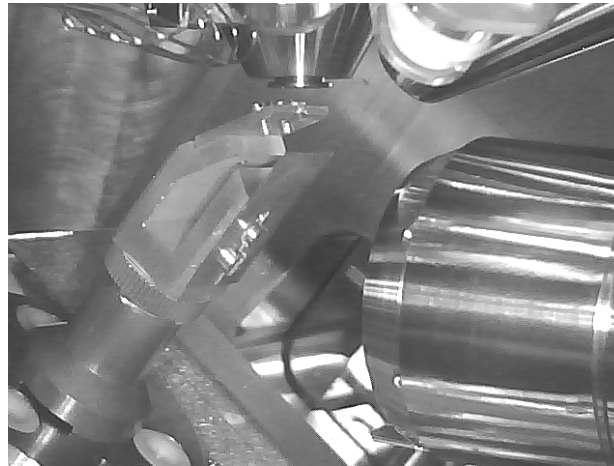
Horizontal stage



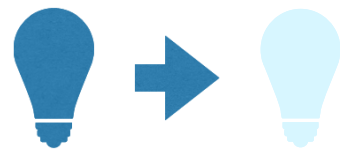
Thin foil



Shield



Holder is pretilted to 60°
Stage inclination 40°
Total sample inclination 20°



Low intensity imaging

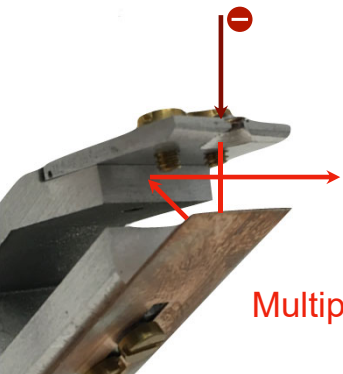
Low intensity TKD imaging with shield

Acquisition parameters:

- 480x480 - no binning
- Gain, 0 (zero)
- Integration time, 100 ms
- Primary beam energy, 30 keV
- Beam current, 16 nA
- EDAX, Hikari camera

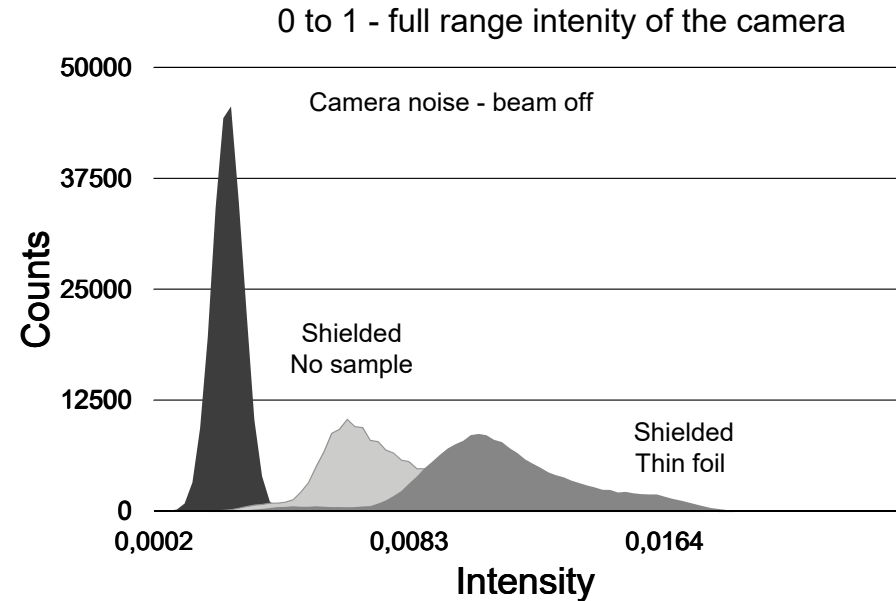
Fraction of the full dynamic range of the camera:

- Camera noise: 0.2%
- Hole/shielded signal: ~1%
- Low intensity pattern: ~2%
- Usually we are running above 10%

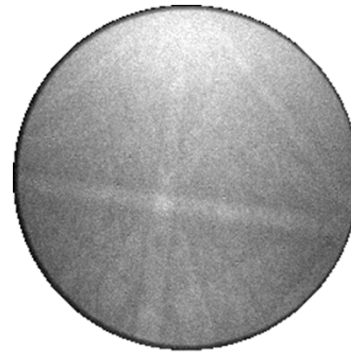


Even for shielded configuration not all re-scattered electrons are removed !!!

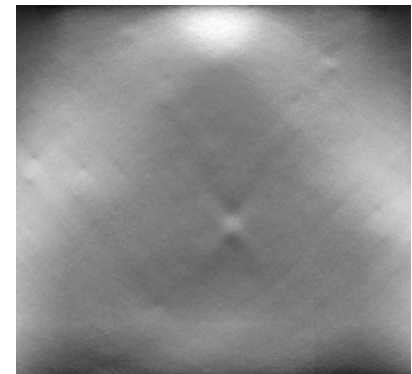
Multiple reflections !!!



Pattern
(histogram stretched)



Hough transformation



How fast can we go?

Highly deformed (0.6 true strain)
stainless steel sample AISI 304

- Electron energy: 30 keV
- Beam current: 16 nA
- Step size: 20 nm
- Saturation of the camera: 20%
- Raw data (no map cleaning)

Camera parameters

Camera binning (pattern resolution)	Camera speed, PPS	Integration time, ms	Average CI
4x4 (120x120)	100	10	0.21
4x4 (120x120)	200 (max)	5	0.13
6x6 (80x80)	300 (max)	3.3	0.12
8x8 (60x60)	360 (max)	2.5	0.12
10x10 (48x48)	450 (max)	2	0.13

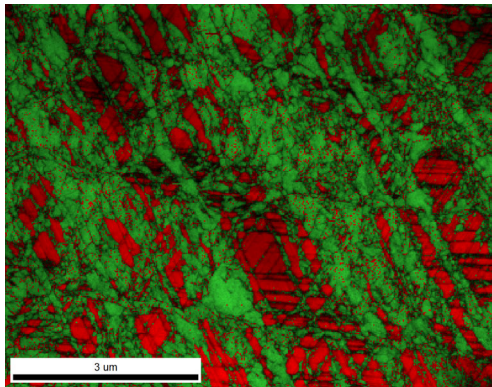
Phase map

Austenite

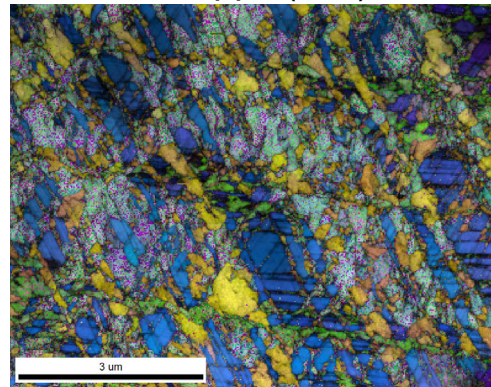
Martensite

Same sample area, different speed and binning, IPF map

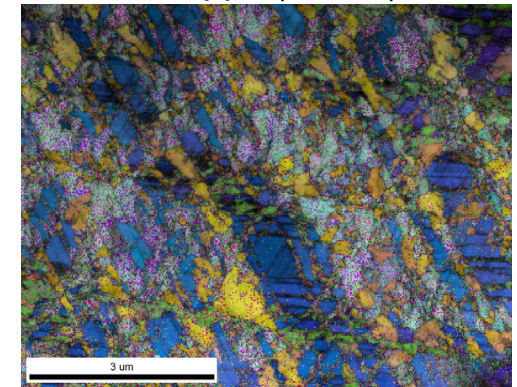
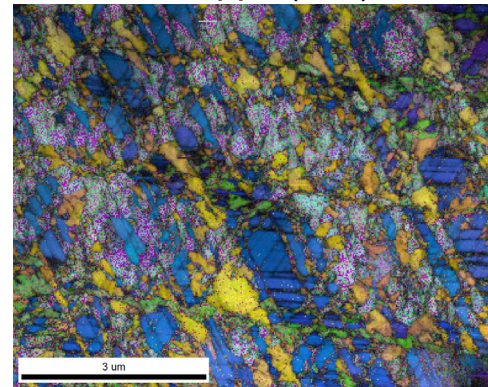
100 pps (4x4)



300 pps (6x6)



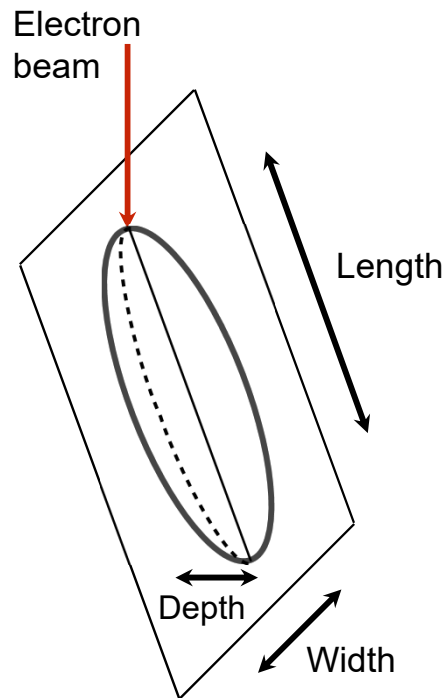
450 pps (48x48)



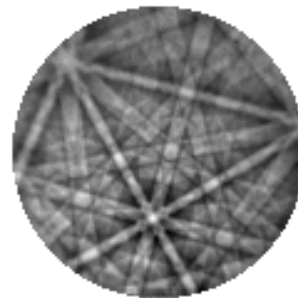
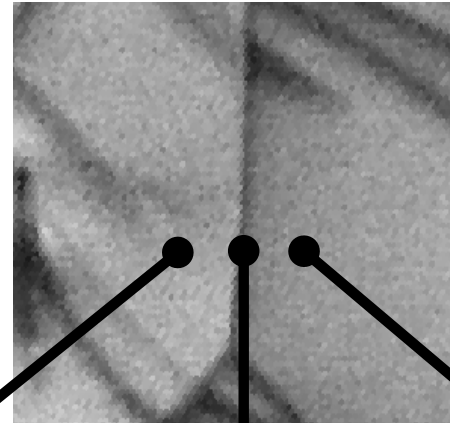


Spatial resolution

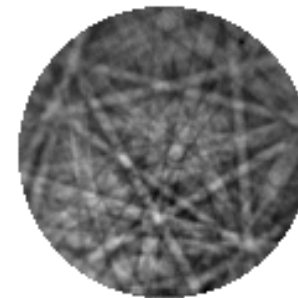
Resolution limits



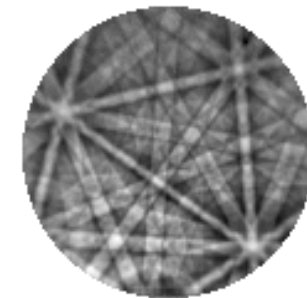
Grain boundary



Good quality



Poor quality

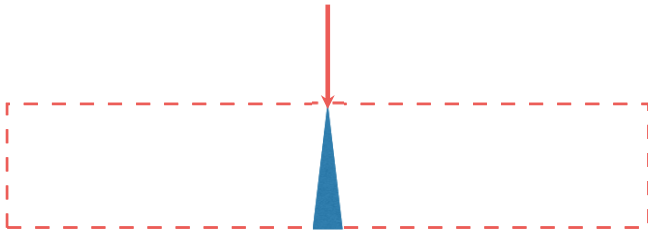
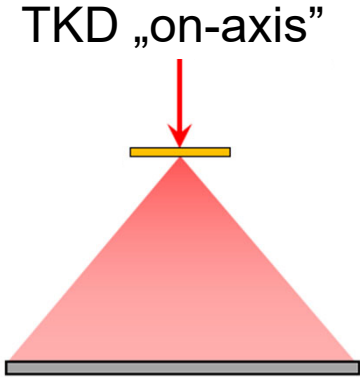


Good quality

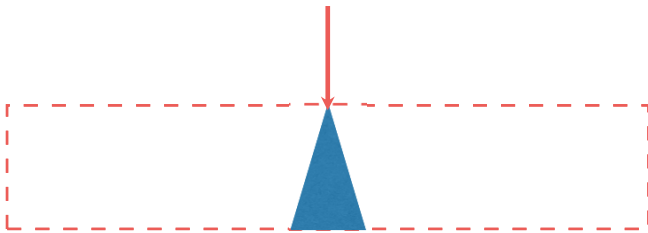
Diffraction quality is substantially deteriorated in the presence of microstructure defects

Distribution of all transmitted electrons on the exit surface of thin foil

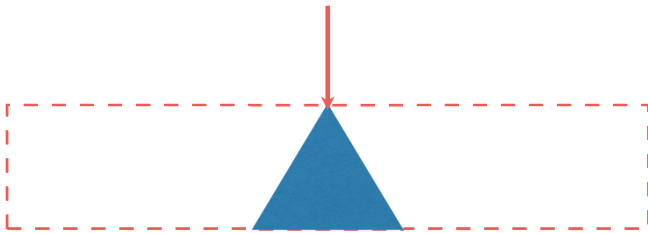
- Diffraction signal originates from the bottom of the foil surface
- Electron sprad depend on the kV and the average sample atomic mass
- If the camera is positioned directly under thin foil symmetry of the measurement setup is not broken and there is only one parameter defining spatial resolution



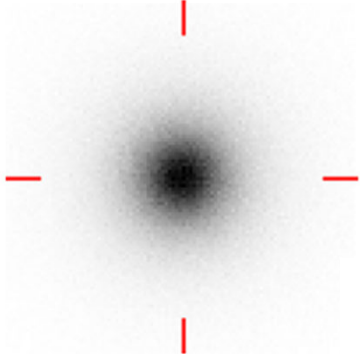
Mg



Fe



Au



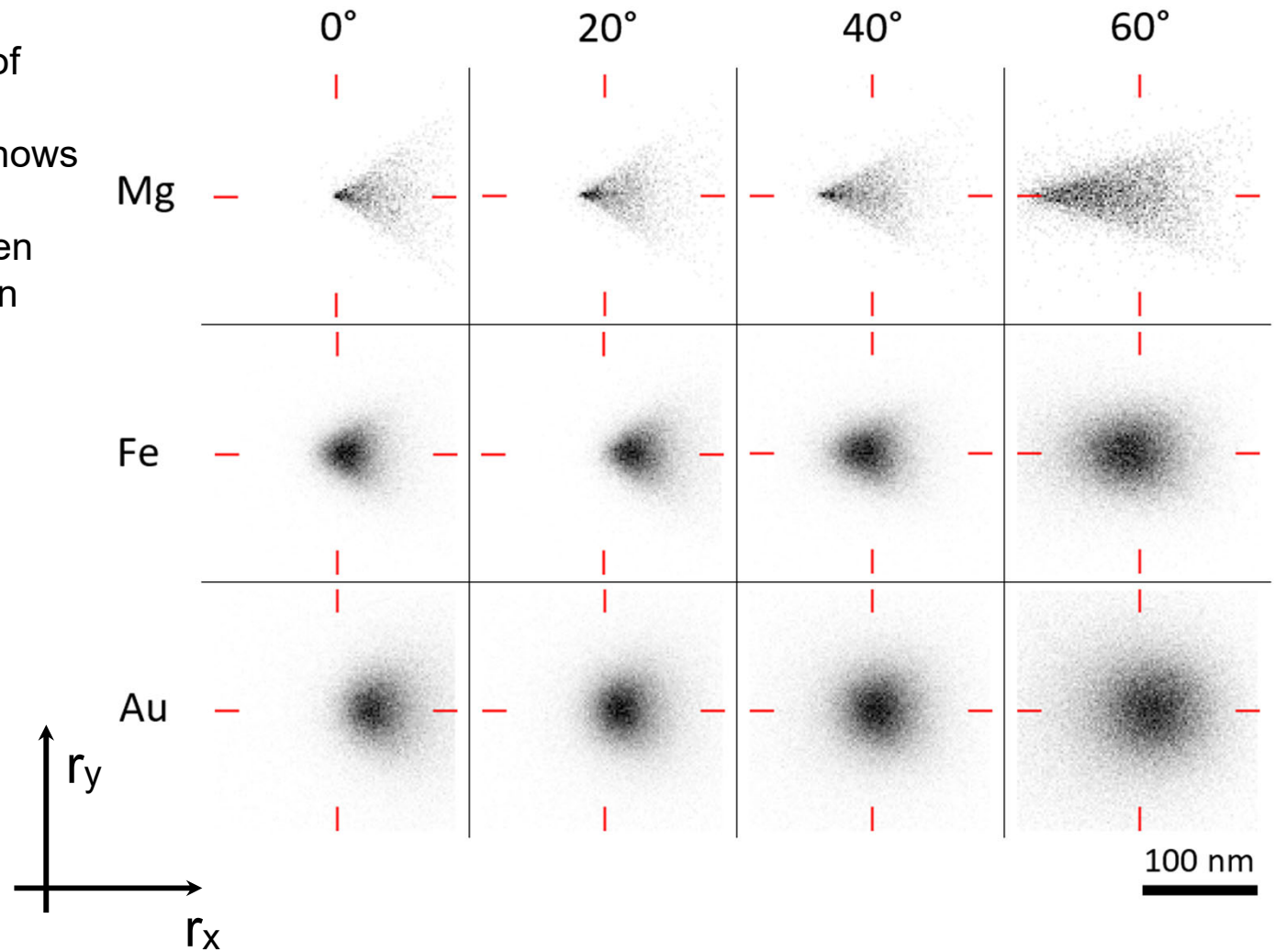
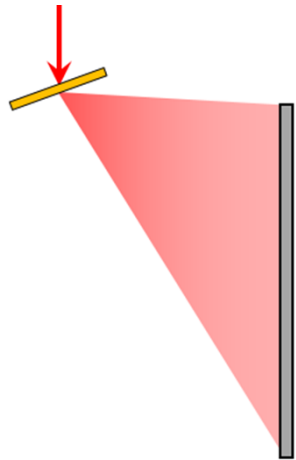
100 nm



Distribution of detected electrons on the exit surface of thin foil

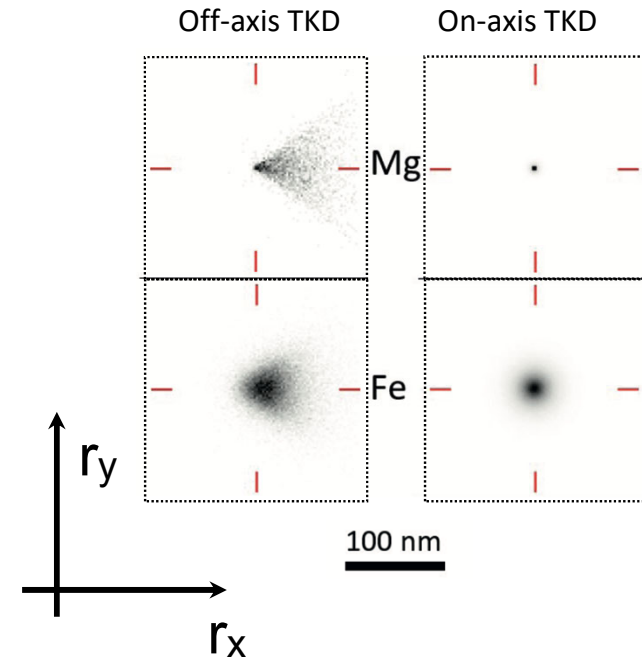
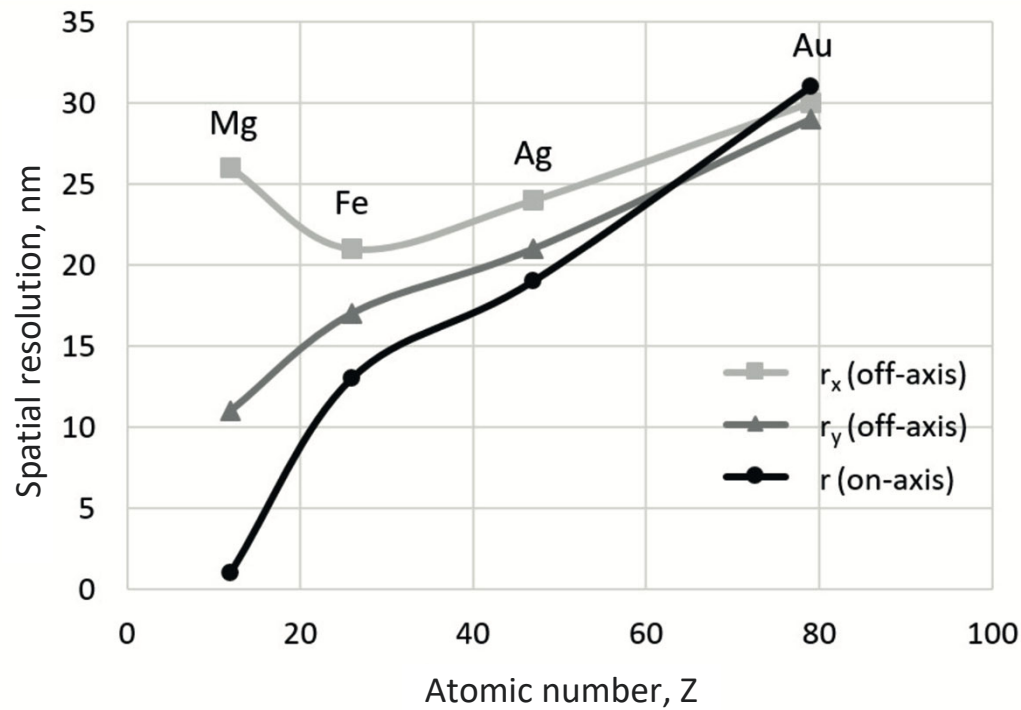
- Camera is positioned on the side of the thin foil
- Distribution of detected electron shows characteristic “comet tail”
- Sample-camera symmetry is broken leading to the two spatial resolution parameters

TKD „off-axis”



Spatial resolution summary

Calculated resolution parameters are based on the electron distribution on the exit foil surface (MonteCarlo simulation)



- For the on-axis setup only one resolution parameter is defined
- For the off-axis setup two resolution parameters are defined



Possible problems with TKD

Foil bending and carbon contamination

Thin foil bending due to stress relaxation - creation of two free surfaces

Carbon contamination due to insufficient speed and/or too small step size



Formation of **FCC**, **BCC**, **HCP** structures
austenite γ , **martensite ϵ** ,
martensite α

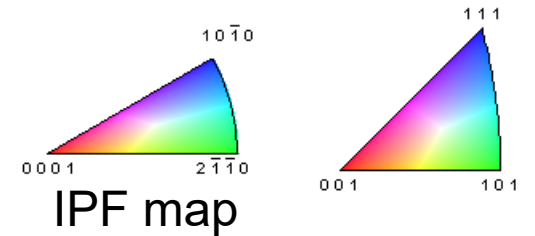
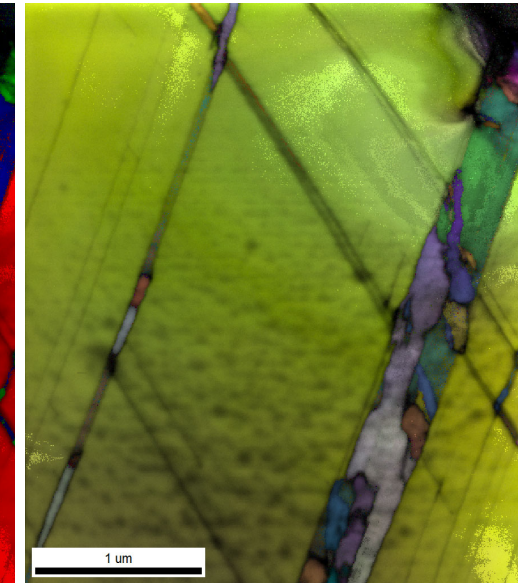
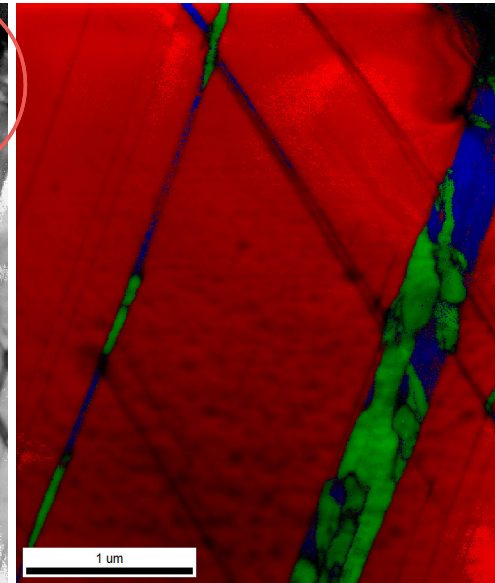
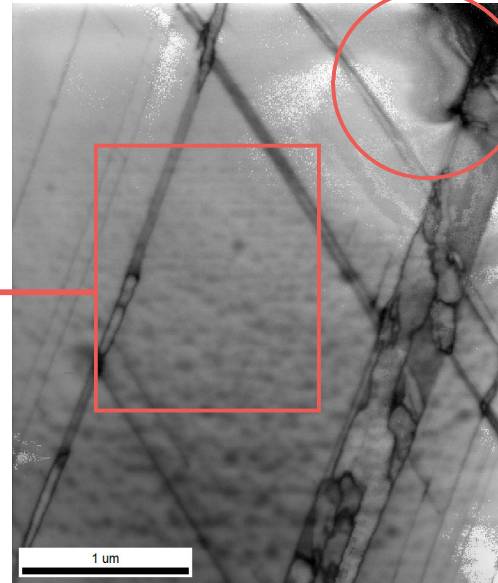


Image Quality map

Phase map

IPF map

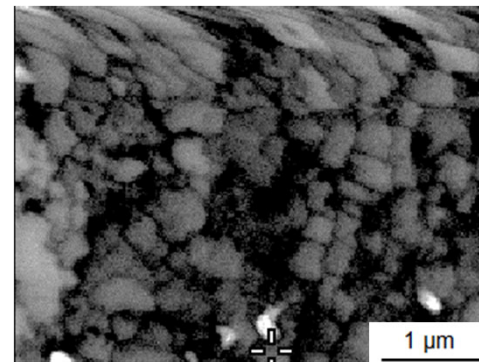
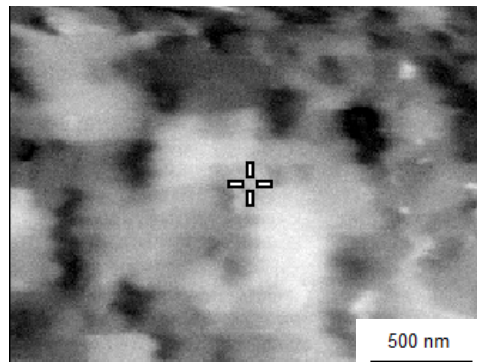


1 um

Deformed stainless-steel sample. Conditions: Beam 30kV, 16nA; Step 5nm; 200pps

Other possible issues

- Mechanical stability of the microscope stage is poor. The SEM stage is designed to handle heavy samples, so high drift is expected. A possible solution is to set the stage in a horizontal position with the proper holder, wait patiently for stage stabilization, or use drift correction if available.
- Electropolishing of the thin foil gives the best results (if it is possible to conduct), however, it creates a wedge sample. In such a case care should be taken to acquire the correct background for compensation.
- FIB sample preparation often creates a significant layer of deformed material on both surfaces. Final polishing on low-kV should be used to remove damaged layers. Alternatively, argon ion polishing can be used as the last thin foil preparation step.
- Thin foil preparation is creating two free surfaces. One should remember that it changes the thermodynamic state of the system and in extreme cases, it can alter material microstructure.

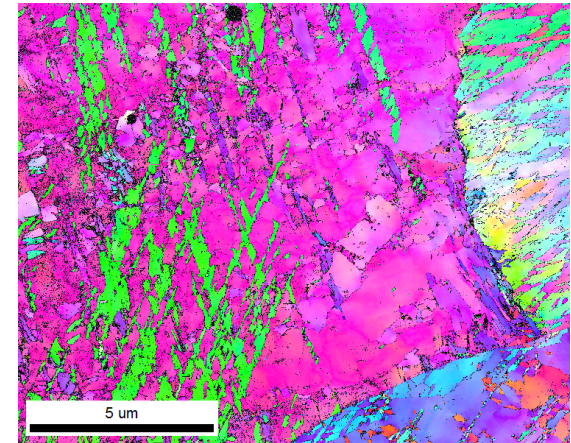


Recommendations

- Prepare good-quality samples. Good sample is 90% of success.
- While using high spatial resolution and collecting large maps use the highest possible mapping speed. Carbon contamination and stage mechanical instability will be reduced.
- If the sample allows use a high current condition of 10nA or more.
- Use a shielded holder to reduce the number of rescattered electrons.
- Set camera intensity to a low level. Raw images in the camera will be dark, thus background correction or histogram equalization is necessary to see Kikuchi bands.
- In the case of the microscope stage having significant backlash, use a horizontal holder with a pre-tilted sample grip section.

If the system is setup correctly you can expect the following:

- Spatial resolution in the range of 10 to 20 nm.
- Acquisition speed within the range of full camera speed for heavy elements.
- Acquisition speed reduced to half of full speed for light elements.

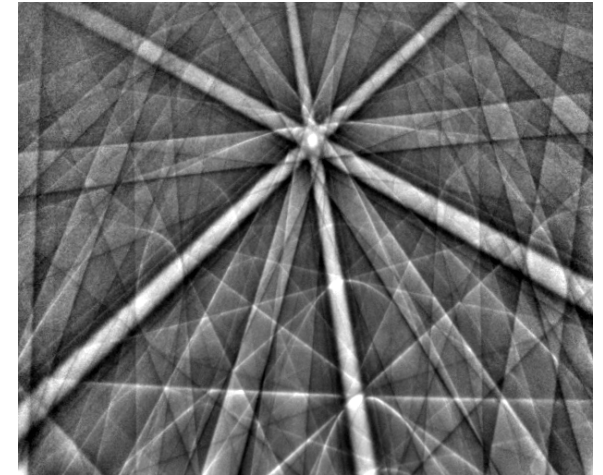


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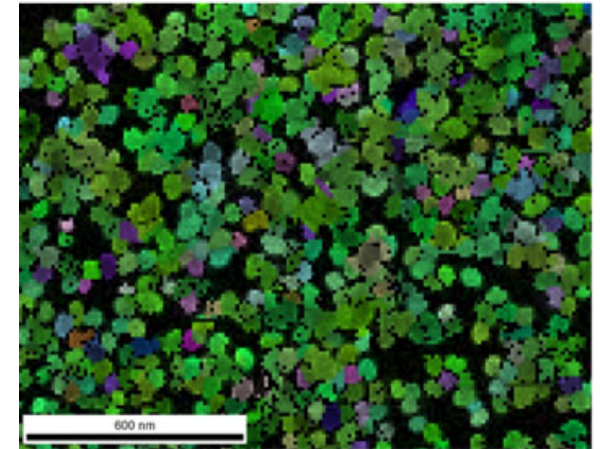


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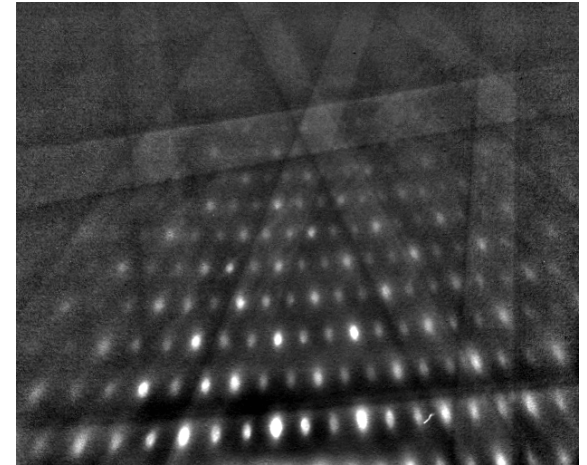


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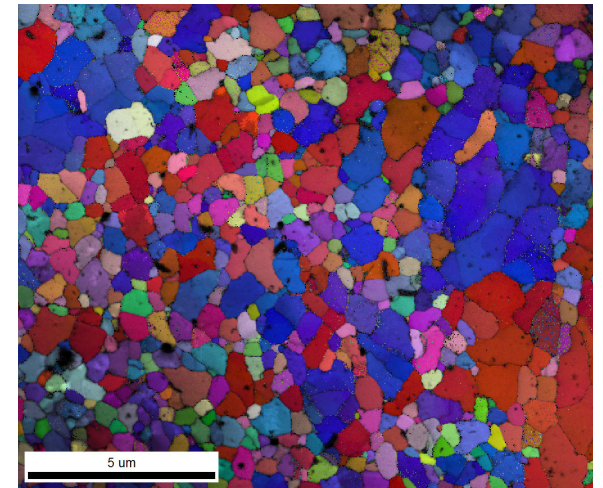


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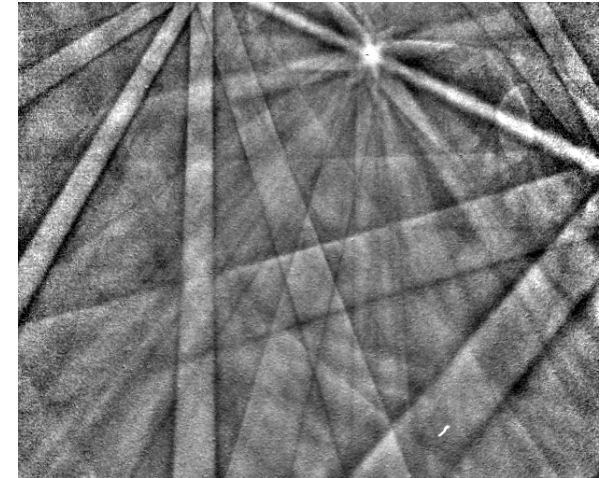


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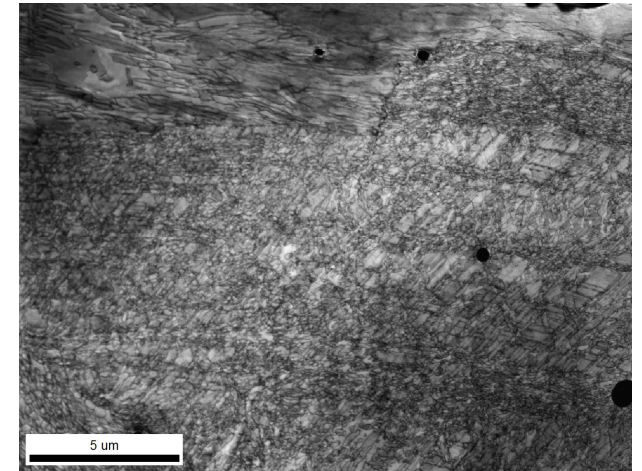


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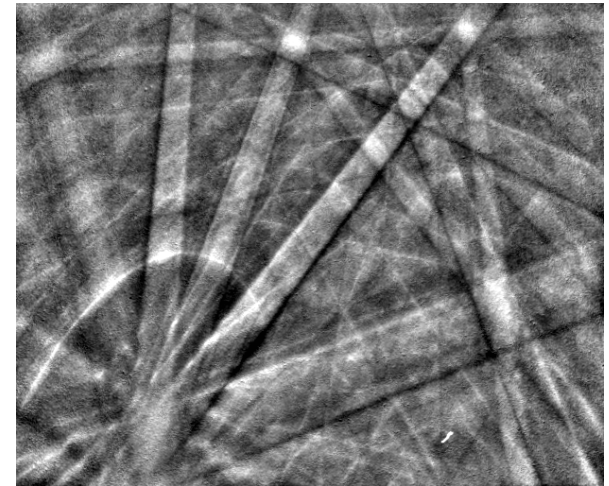


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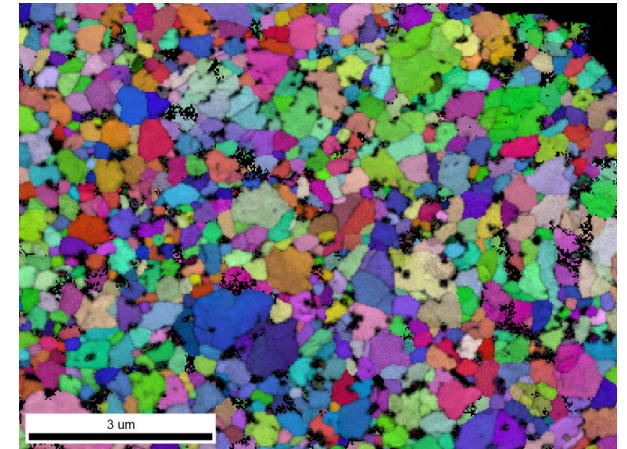


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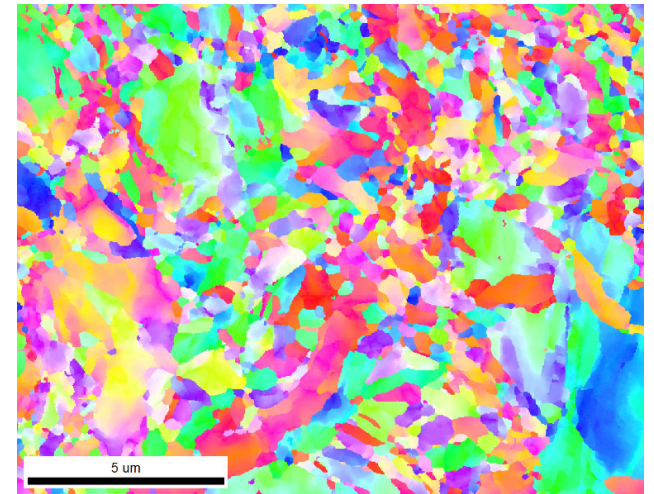


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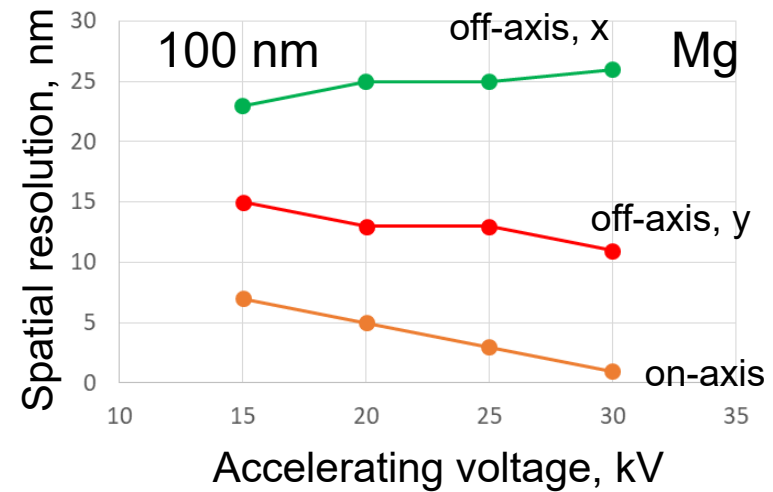
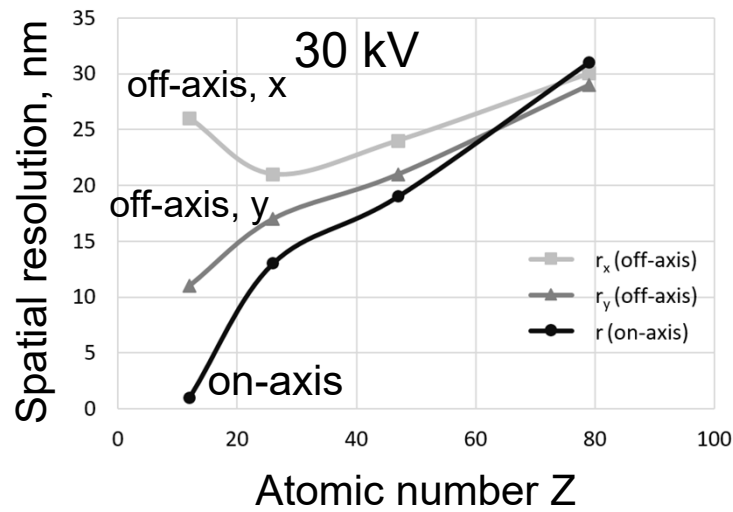
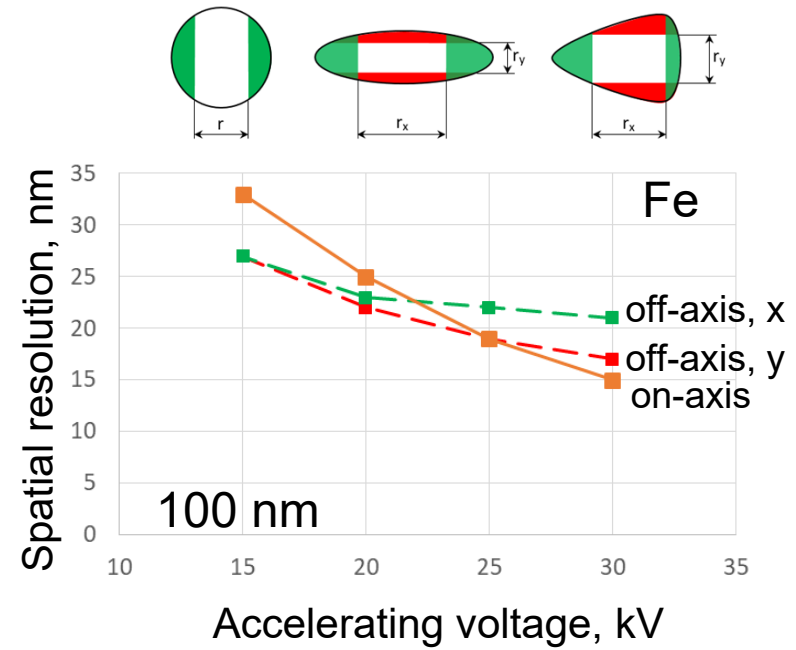
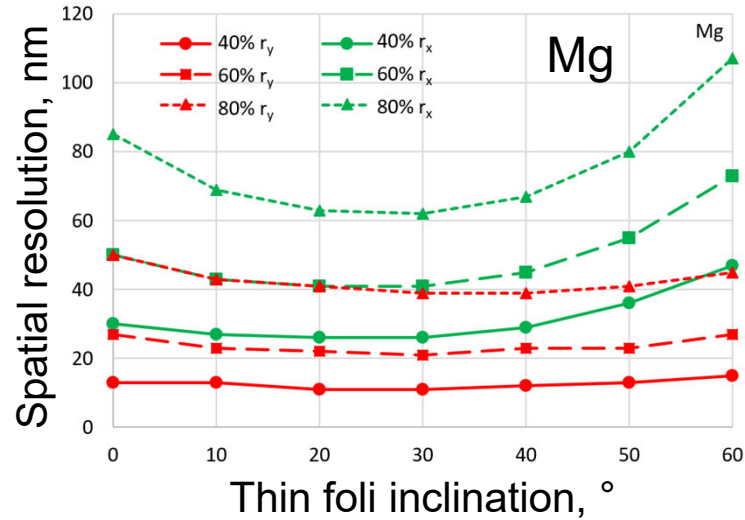
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Spatial resolution - simulation



Electron yield in the EBSD camera, Fe sample

EBSD camera intensity

